TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

TLP131

Office Machine
Programmable Controllers
AC / DC-Input Module
Telecommunication

The TOSHIBA mini flat coupler TLP131 is a small outline coupler, suitable for surface mount assembly.

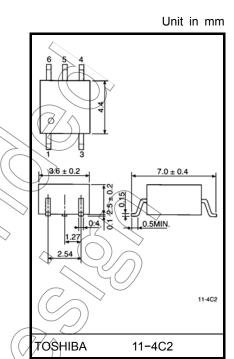
TLP131 consists of a photo transistor, optically coupled to a gallium arsenide infrared emitting diode.

- Collector-emitter voltage: 80V (min.)
- Current transfer ratio: 50% (min.)

Rank GB: 100% (min.)

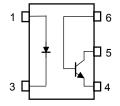
- Isolation voltage: 3750Vrms (min.)
- UL recognized: UL1577, file No. E67349

TLP131 base terminal is for the improvement of speed, reduction of dark current, and enable operation.



Weight: 0.09 g (typ.)

Pin Configurations (top view)



- 1 : Anode
- 3 : Cathode
- 4 : Emitter
- 5 : Collector
- 6 : Base



Current Transfer Ratio

Туре	Classification	Ratio (I _C	Transfer o (%) / I _F) = 5V, Ta = 25°C	Marking Of Classification		
		Min.	Max.			
	(None)	50	600	BLANK, Y, Y", G, G", B, B", GB		
TLP131	Rank Y	50	150	Y, Y*		
TEI 101	Rank GR	100	300	G, G"		
	Rank GB	100	600	G, G ^a , B, B ^a , GB		

Note: Application type name for certiffication test, please use standard product type name, i.e. TLP131(GB): TLP131

Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	IF (V/	50 🛇	(mA
	Forward current derating (Ta≥53°C)	ΔIFI°C	-0.7	mA/°C/
LED	Peak forward current (100µs pulse,100pps)	IFP	1	A
	Reverse voltage	(V _R)	5) ∨
	Junction temperature		125	°C
	Collector-emitter voltage	VCEO	80	V
	Collector-base voltage	V _{CBO} //	80	V
	Emitter-collector voltage	V _{ECO}	7)	V
or	Emitter-base voltage	V _{EBO}	7	V
Detector	Collector current	lc 🔨	50	mA
D	Peak collector current (10ms pulse,100pps)	lop	100	mA
	Power dissipation	PG	150	mW
	Power dissipation derationg (Ta ≥ 25°C)	APc/°C	-1.5	mW / °C
	Junction temperature	(\(\tau_j\))	125	°C
Stor	age temperature range	T _{stg}	-55~125	°C
Ope	erating temperature range	T_{opr}	-55~100	°C
Lead soldering temperature (10s)		T _{sol}	260	°C
Total package power dissipation		PT	200	mW
Tota	al package power dissipation derating (Ta ≥ 25°C)	ΔP _T / °C	-2.0	mW / °C
Isola	ation voltage (AC, 1min., RH≤ 60%) (Note 1)	BVS	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1) Device considered a two terminal device: Pins 1 and 3 shorted together, and pins 4, 5 and 6 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V _{CC}	_	5	48	V
Forward current	lF	_	16	25	mA
Collector current	IC	_	1	10	mA
Operating temperature	T _{opr}	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	V _F	I _F = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	I _R	V _R = 5 (-((10	μΑ
	Capacitance	C _T	V = 0, f = 1 MHz	1	30	/ _	pF
	Collector–emitter breakdown voltage	V _{(BR)CEO}	C = 0:5mA	8)	ı	٧
	Emitter–collector breakdown voltage	V _{(BR)ECO}	IE = 0,1mA		1	ı	>
	Collector-base breakdown voltage	V(BR)CBO	I _C = 0.1mA	80	_		>
	Emitter-base breakdown voltage	V(BR)EBO	1 _E = 0.1mA	7	_		٧
Detector	collector dark current	loco local	V _{CE} = 48V	ı	10	100	nA
Dete	collector dark current	ICEO	V _{CE} = 48V,Ta = 85°C	ı	2	50	μΑ
	Collector dark current	ICER	V _{CE} = 48V, Ta = 85°C R _{BE} = 1MΩ	ı	0.5	10	μΑ
	Collector dark current	I _{CBO}	V _{CB} = 10V	_	0.1		nA
	DC forward current gain	h _{FE}	$V_{CE} = 5V_{IC} = 0.5mA$	_	400	_	
	Capacitance (collector to emitter)	CCE	V = 0, f = 1MHz	_	10	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Current transfer ratio	4	I _F = 5 mA, V _{CE} = 5 V	50	_	600	%
Current dansier (allo	1C / IF	Rank GB	100	_	600	
Saturated CTR	Ic/ I _{F (sat)}	I _F = 1 mA, V _{CE} = 0.4 V Rank GB	l	60	_	%
Caluated GHZ	F (sat)		30	_	_	
Base photo-current	l _{PB}	$I_F = 5mA, V_{CB} = 5V$	ı	10	_	μΑ
	VCE (sat)	I _C = 2.4 mA, I _F = 8 mA	l	_	0.4	
Collector–emitter saturation voltage		I _C = 0.2 mA, I _F = 1 mA Rank GB	ı	0.2	_	V
-				_	0.4	
Off-state collector current	I _{C (off)}	I _F = 0.7mA, V _{CE} = 48 V	_	1	10	μΑ

3

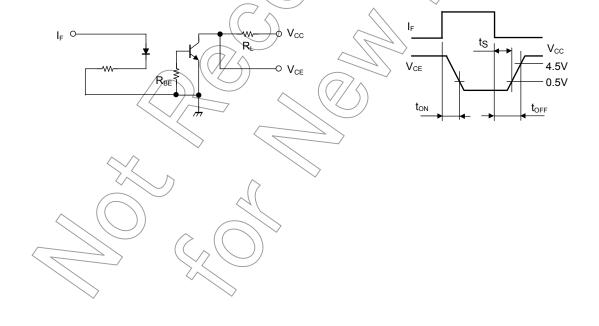
Isolation Characteristics (Ta = 25°C)

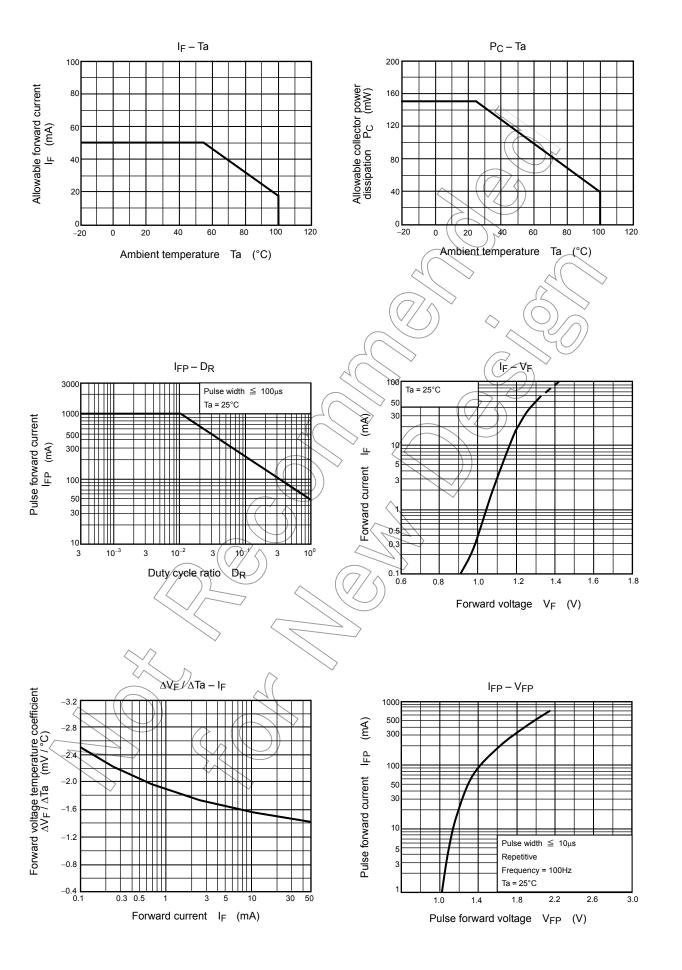
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance (input to output)	CS	V _S = 0, f = 1 MHz	_	8.0	_	pF
Isolation resistance	R _S	V _S = 500 V	5×10 ¹⁰	10 ¹⁴	_	Ω
	BVS	AC, 1 minute	3750	_	_	Vrms
Isolation voltage		AC, 1 second, in oil		10000	_	VIIIIS
		DC, 1 minute, in oil	(F	10000	_	Vdc

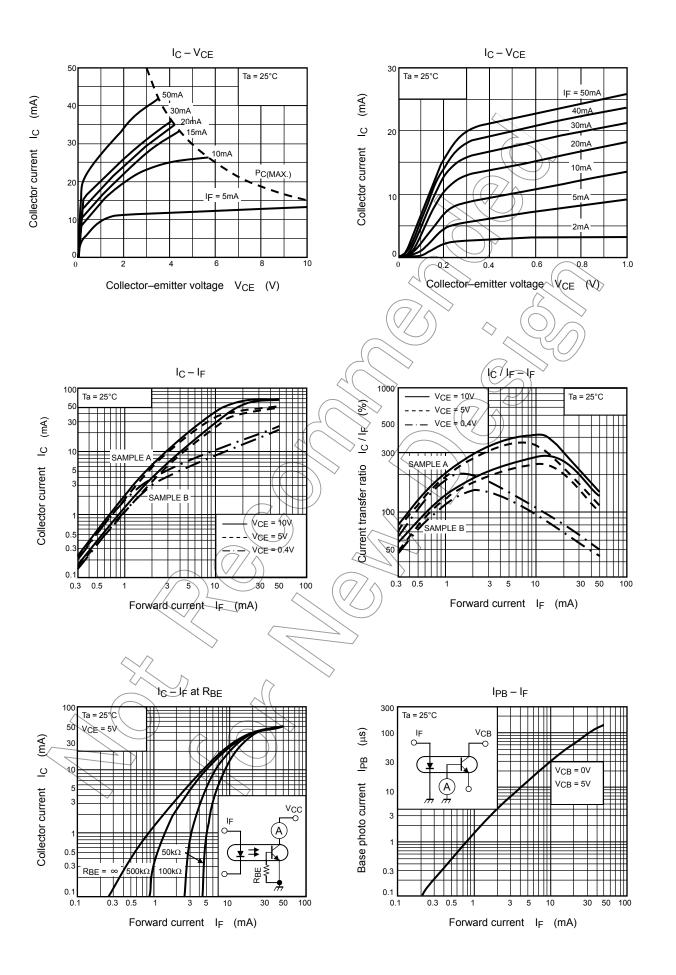
Switching Characteristics (Ta = 25° C)

		21				
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Rise time	t _r		_	2	_	
Fall time	t _f	V _{CC} = 10 V, I _C = 2 mA		< 3	\rightarrow	μs
Turn-on time	t _{on}	$R_L = 100\Omega$	-	3	> -	μδ
Turn-off time	t _{off}		7))3) —	
Turn-on time	ton	$R_L = 1.9 (\Omega\%)$ (Fig.1)	/	(2/	_	
Storage time	ts	RBE = OPEN VCC = 5 V, I _F = 16 mA		25	_	μs
Turn-off time	toff	VCC = 5 V, 1E = 10 MA	(-))	40	_	
Turn-on time	ton	$R_L = 1.9 \text{ k}\Omega\%$ (Fig.1)	<u> </u>	2	_	
Storage time	t _s	RBE = 220 kΩ VCC \Rightarrow 5 V, I _F = 16 mA	/ _	20	_	μs
Turn-off time	toff	VCC ₹ 5 V, IF = 10 MA	_	30	_	

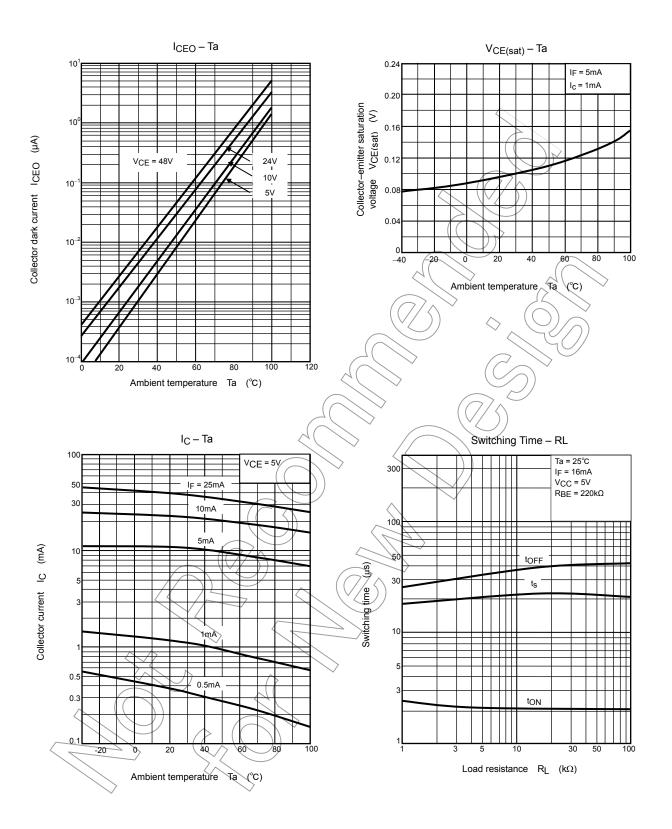
Fig. 1 Switching time test circuit

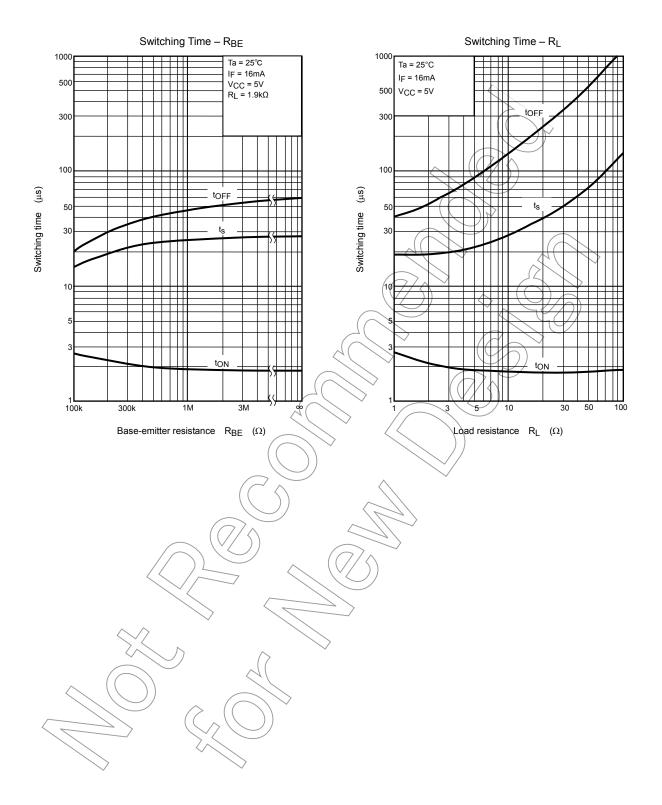






6 2007-10-01





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9